HMC826LP6CE

FRACTIONAL-N SYNTHESIZER WITH INTEGRATED VCO, 990 - 1105 MHz

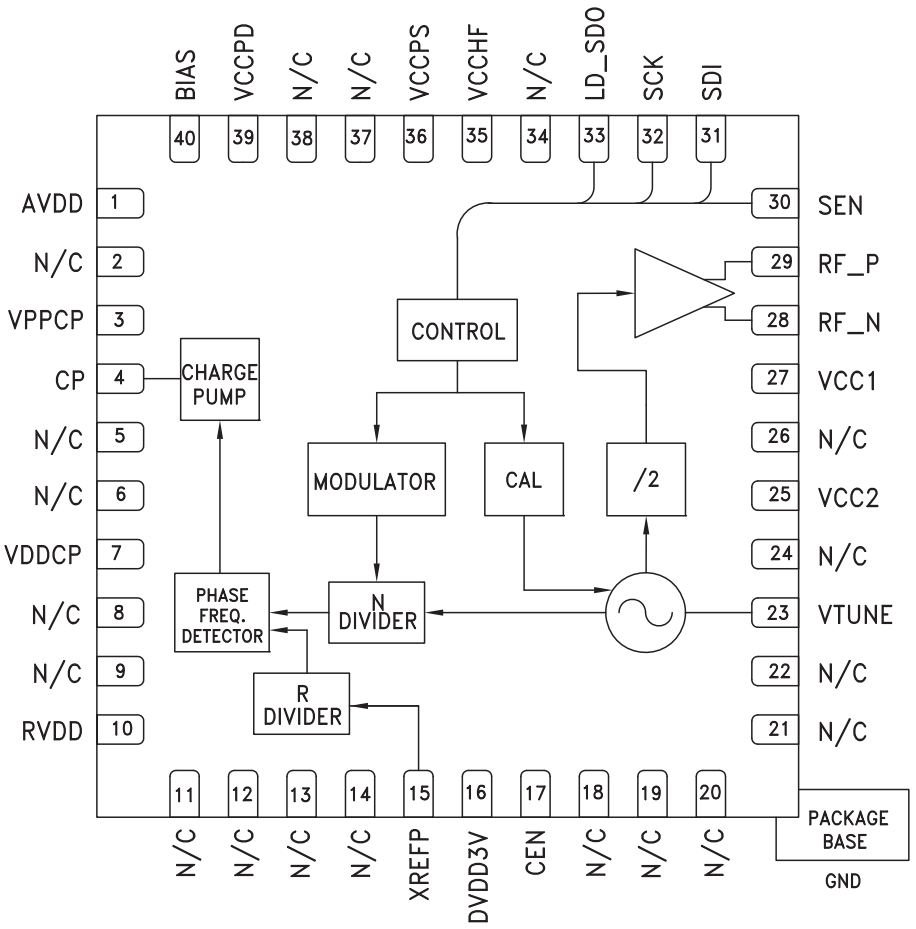
Features

- RF Bandwidth: 990 to 1105 MHz
- Fractional or Integer Modes
- 19-Bit Prescaler
- Ultra Low Phase Noise
  -110 dBc/Hz in Band Typ.
- Figure of Merit (FOM)
  -227 dBc Integer
- 24-bit Step Size, Resolution 3 Hz typ
- 200 MHz, 14-bit Reference Path Input
- Cycle Slip Prevention
- Read / Write Serial Port, Chip ID
- 40 Lead 6x6mm SMT Package: $36mm^2$

Typical Applications

- Cellular/4G Infrastructure
- Repeaters and Femtocells
- Communications Test Equipment
- CATV Equipment
- Phased Array Applications
- DDS Replacement
- Very High Data Rate Radios

Functional Diagram



General Description

The HMC826LP6CE is a fully functioned Fractional-N Phase-Locked-Loop (PLL) Frequency Synthesizer with an Integrated Voltage Controlled Oscillator (VCO). The synthesizer consists of an integrated low noise VCO with divide-by-2 output, an autocalibration subsystem for low voltage VCO tuning, a very low noise digital Phase Detector (PD), a precision controlled charge pump, a low noise reference path divider and a fractional divider.

The fractional synthesizer features an advanced delta-sigma modulator design that allows both ultra-fine step sizes and low spurious products. The phase detector (PD) features cycle slip prevention (CSP) technology to allow faster frequency hopping times. Ultra low in-close phase noise and low spurious also allows wider loop bandwidths for faster frequency hopping and low micro-phonics.

For theory of operation and register map refer to the "PLLs w/ Integrated VCOs - RF VCOs" Operating Guide. To view the Operating Guide, please visit www.hittite.com and choose HMC826LP6CE from the "Search by Part Number" pull down menu.

Electrical Specifications, T_A = +25° C

VPPCP, VDDCP, VCC1, VCC2 = 5V ±4%; RVDD, AVDD, DVDD3V, VCCPD, VCCHF, VCCPS = 3.3V ±6% GNDCP = GNDLS = Ground Paddle = 0V

Parameter	Condition	Min.	Typ.	Max.	Units
RF Output Characteristics					
VCO Frequency at PLL Input		1980		2210	MHz
RF Output Frequency at $f_{VCO}/2$		990		1105	MHz
RF Output Power at $f_{VCO}/2$		8	11	15	dBm
VCO Tuning Sensitivity	Measured at 2 GHz, 2V		15		MHz/V
VCO Supply Pushing	Measured at 2 GHz, 2V	-2		1.5	MHz/V
RF Output 2nd Harmonic			-25		dBc
RF Output 3rd Harmonic			-23		dBc
RF Output 4th Harmonic			-31		dBc
RF Output 5th Harmonic			-33		dBc
RF Divider Characteristics					
19-Bit N-Divider Range (Integer)	Max = 2^{19} - 1	16		524,287	
19-Bit N-Divider Range (Fractional)	Fractional nominal divide ratio varies (-3 / +4) dynamically max	20		524,283	
REF Input Characteristics					
Max Rep Input Frequency		200			MHz
Max Ref Frequency with AutoCal			54		MHz
Min Ref Input Frequency			100		kHz
Ref Input Range	AC Coupled	1.5	2	3.3	Vpp
Ref Input Capacitance				5	pF
14-Bit R-Divider Range		1		16,383	
Phase Detector (PD)					
PD Frequency Fractional Mode	Max PD Freq. Min VCO Freq/20	0.1		88	MHz
PD Frequency Integer Mode	Max PD Freq. Min VCO Freq/16	0.1		110	MHz
Charge Pump					
Max Output Current			2		mA
Min Output Current			500		µA
Charge Pump Gain Step Size (5-Bits)			500		µA

Electrical Specifications (Continued)

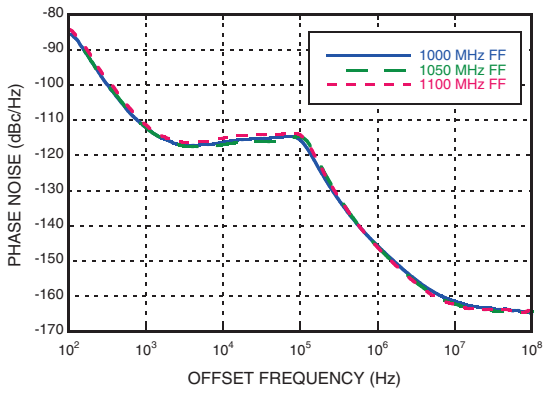
Parameter	Condition	Min.	Typ.	Max.	Units
Charge Pump Trim Step Size (3-Bits)			7		µA
Charge Pump Offset Step Size (4-Bits)			55		µA
PD/Charge Pump Noise	50 MHz Ref, Input Referred, Integer, add 6 dB for Fractional				
1 kHz			-141		dBc/Hz
10 kHz			-149		dBc/Hz
100 kHz			-155		dBc/Hz
Compliance Voltage	Less than 3 dB degradation typ. at these limits				
	-385 µA Offset	0.4		VPPCP-0.8	V
	+385 µA Offset	0.8		VPPCP-0.4	V
Logic Inputs					
VIH Input High Voltage		DVDD3V-0.4		DVDD3V	V
VIL Input Low Voltage		0		0.4	V
Logic Outputs					
VOH Output High Voltage		DVDD3V-0.4		DVDD3V	V
VOL Output Low Voltage		0		0.4	V
Power Supply Voltages					
Analog 3.3V Supplies	AVDD, VCCHF, VCCPS, VCCPD, RVDD	3.0	3.3	3.5	V
Digital Supply	DVDD3V	3.0	3.3	3.5	V
Analog 5V Supplies	VPPCP, VDDCP, VCC1, VCC2	4.8	5	5.2	V
Power Supply Currents					
+5V Analog Charge Pump	VPPCP, VDDCP		5.3		mA
+5V VCO Core and PLL Buffer	VCC2		56		mA
+5V VCO Divider and RF Buffer	VCC1		36		mA
+3.3V Analog	AVDD, VCCHF, VCCPS, VCCPD, RVDD		45		mA
+3.3V Digital	DVDD3V		6.5		mA
Power Down - Crystal Off	Reg 01h=0, Crystal Not Clocked		10		µA
Power Down - Crystal On, 100 MHz	Reg 01h=0, Crystal Clocked 100 MHz		10	200	µA
Power on Reset					
Typical Reset Voltage on DVDD			700		mV
Min DVDD Voltage for No Reset		1.5			V
Power on Reset Delay			250		µs
VCO Open Loop Phase Noise at fvco/2					
1 GHz Divide-by-2 Output	10 kHz Offset		-91		dBc/Hz
1 GHz Divide-by-2 Output	100 kHz Offset		-121		dBc/Hz
1 GHz Divide-by-2 Output	1 MHz Offset		-146		dBc/Hz
1 GHz Divide-by-2 Output	10 MHz Offset		-163		dBc/Hz
1 GHz Divide-by-2 Output	100 MHz Offset		-164		dBc/Hz
Closed Loop Phase Noise PLL + VCO at fvco/2					
1 GHz VCO, Integer, 50 MHz PFD	1 kHz Offset		-112		dBc/Hz

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:
20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373
Order On-line at www.hittite.com

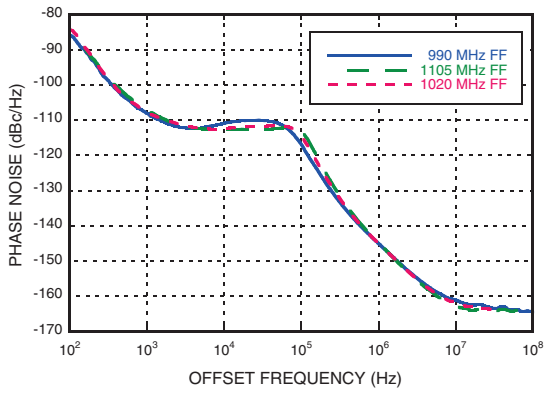
Electrical Specifications (Continued)

Parameter	Condition	Min.	Typ.	Max.	Units
1 GHz VCO, Integer, 50 MHz PFD	10 kHz Offset		-114		dBc/Hz
1 GHz VCO, Integer, 50 MHz PFD	100 kHz Offset		-120		dBc/Hz
1 GHz VCO, Integer, 50 MHz PFD	1 MHz Offset		-146		dBc/Hz
1 GHz VCO, Fractional, 50 MHz PFD	1 kHz Offset		-107		dBc/Hz
1 GHz VCO, Fractional, 50 MHz PFD	10 kHz Offset		-107		dBc/Hz
1 GHz VCO, Fractional, 50 MHz PFD	100 kHz Offset		-112		dBc/Hz
Figure of Merit	Normalized 1 Hz				
Integer Mode	Measured w/ 50 MHz PD at 30 kHz Offset		-227		dBc/Hz
Fractional Mode	Measured w/ 50 MHz PD at 30 kHz Offset		-225		dBc/Hz

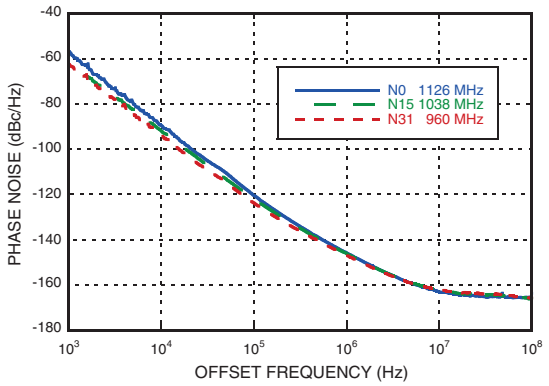
Closed Loop Integer Phase Noise



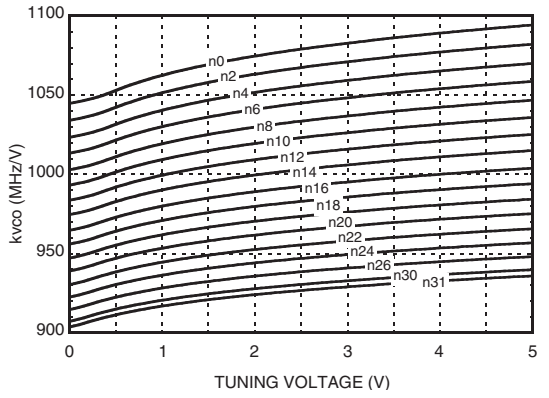
Typical Closed Loop Fractional Phase Noise [1]



VCO/2 Free Running Phase Noise

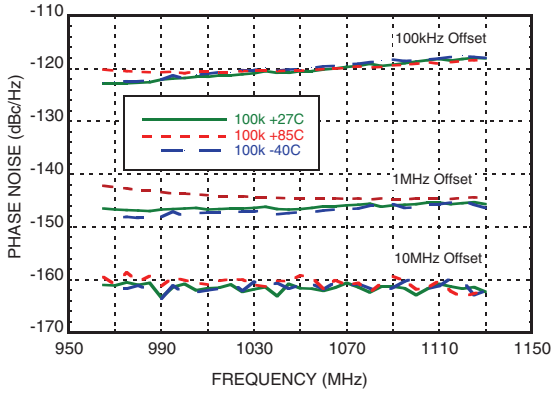


Typical VCO/2 Tuning Curves vs. Switch Position

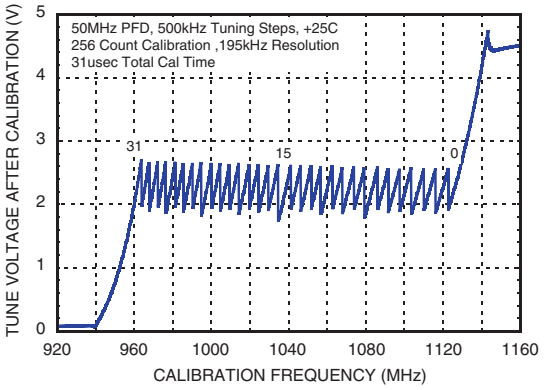


[1] Fractional Mode, 50 MHz Crystal, R=1, ~80 kHz Loop BW, Filter C36 = 560pF, R26 = 680Ω, C35 =15nF, R27 & R28 = 1 kΩ, C37 & C38 = 270 pF, 2mA Charge Pump, -385µA Offset.

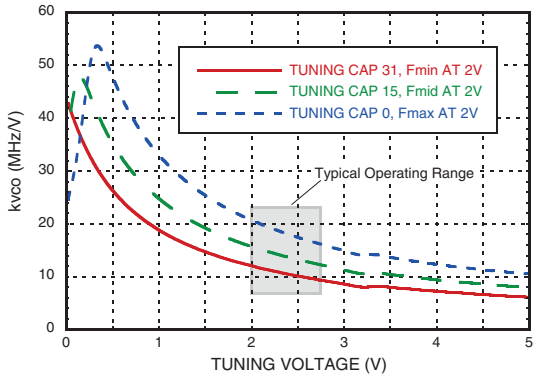
Free Running VCO Phase Noise (V_{TUNE} Set by AutoCal)



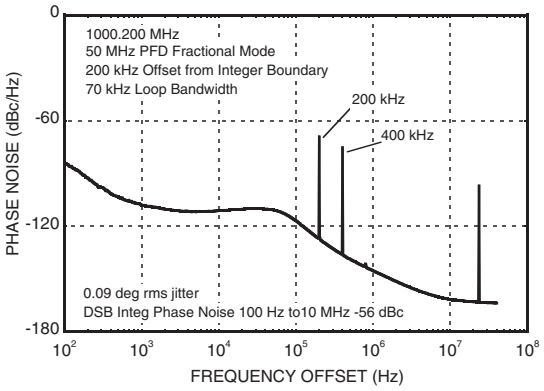
Typical VCO Tuning Voltage After Calibration



Typical VCO Sensitivity vs. Cap @ Fo Voltage



Typical Spurious at 200 kHz from Integer Boundary [1]



Typical Output Power - Narrow Band Match

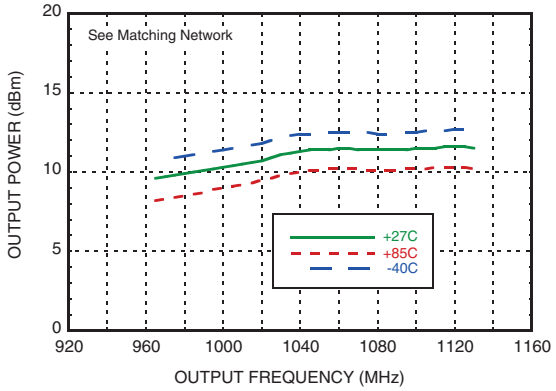
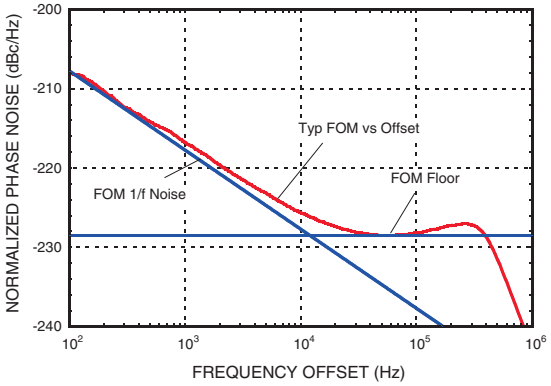


Figure of Merit



[1] Fractional Mode, 50 MHz Crystal, R=1, ~80 kHz Loop BW, (Loop filter values: C36 = 560pF, R26 = 680Ω, C35 =15nF, R27 & R28 = 1 kΩ, C37 & C38 = 270 pF) 2mA Charge Pump, -385µA Offset.

Pin Descriptions

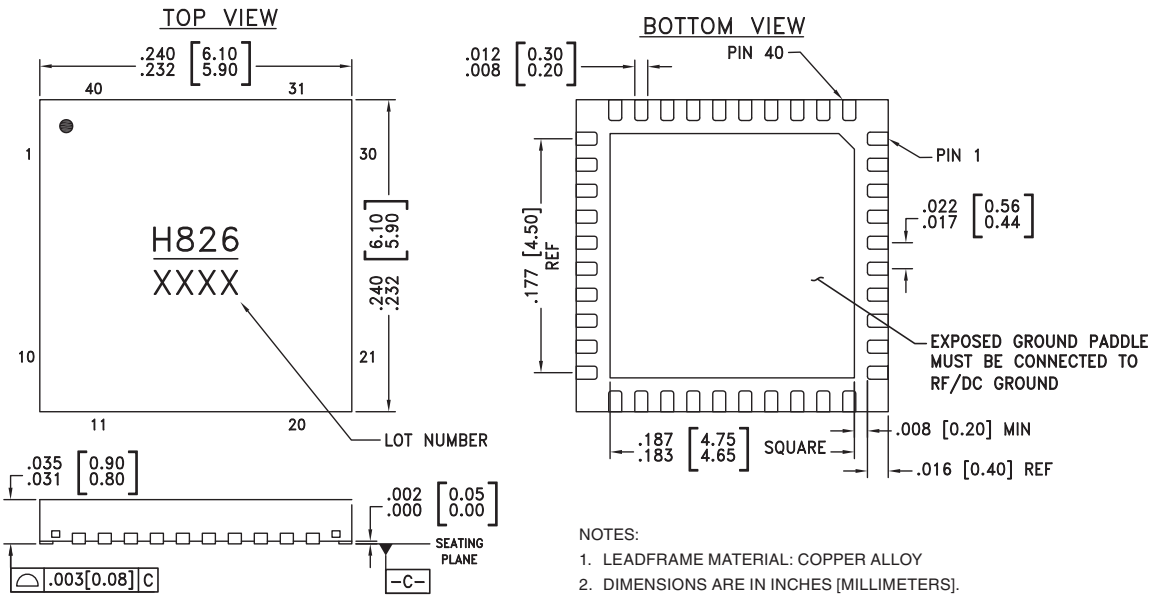
Pin Number	Function	Description
1	AVDD	DC Power Supply for analog circuitry.
2, 5, 6, 8, 9, 11 - 14, 18 - 22, 24, 26, 34, 37, 38	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.
3	VPPCP	Power Supply for charge pump analog section
4	CP	Charge Pump Output
7	VDDCP	Power Supply for the charge pump digital section
10	RVDD	Reference Supply
15	XREFP	Reference Oscillator Input
16	DVDD3V	DC Power Supply for Digital (CMOS) Circuitry
17	CEN	Chip Enable. Connect to logic high for normal operation.
23	VTUNE	VCO Varactor. Tuning Port Input.
25	VCC2	VCO Analog Supply 2
27	VCC1	VCO Analog Supply 1
28	RF_N	VCO Divide by 2 RF Positive Output
29	RF_P	VCO Divide by 2 RF Negative Output
30	SEN	PLL Serial Port Enable (CMOS) Logic Input
31	SDI	PLL Serial Port Data (CMOS) Logic Input
32	SCK	PLL Serial Port Clock (CMOS) Logic Input
33	LD_SDO	Lock Detect, or Serial Data, or General Purpose (CMOS) Logic Output (GPO)
35	VCCHF	DC Power Supply for Analog Circuitry
36	VCCPS	DC Power Supply for Analog Prescaler
39	VCCPD	DC Power Supply for Phase Detector
40	BIAS	External bypass decoupling for precision bias circuits. Note: 1.920V ±20mV reference voltage (BIAS) is generated internally and cannot drive an external load. Must be measured with 10GΩ meter such as Agilent 34410A, normal 10MΩ DVM will read erroneously.

Absolute Maximum Ratings

AVDD, RVDD, DVDD3V, VCCPD, VCCHF, VCCPS	-0.3V to +3.6V
VPPCP, VDDCP, VCC1	-0.3V to +5.8V
VCC2	-0.3V to +5.5V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to 125°C
Maximum Junction Temperature	150°C
Reflow Soldering	
Peak Temperature	260°C
Time at Peak Temperature	40 sec
ESD Sensitivity (HBM)	Class 1B

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Outline Drawing



NOTES:

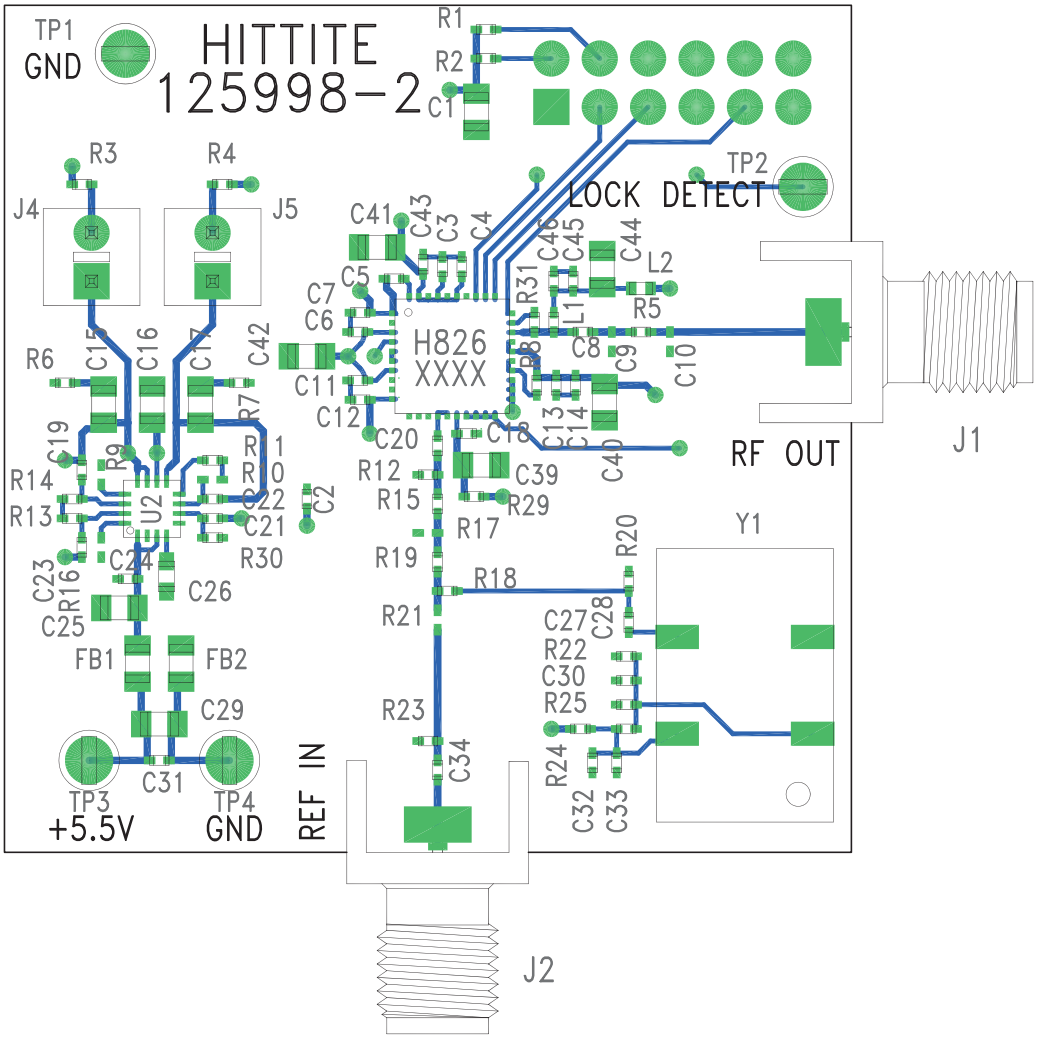
1. LEADFRAME MATERIAL: COPPER ALLOY
2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [1]
HMC826LP6CE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL3	H826 XXXX

[1] 4-Digit lot number XXXX

Evaluation PCB



The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

List of Materials for Evaluation PCB 128147 [1]

Item	Description
J1, J2	PCB Mount SMA RF Connector
J3	Dual Row Terminal Strip
J4, J5	Connector Header
C1, C15 - C17, C25, C29	10 µF Capacitor, 0805 Pkg.
C2, C3, C6, C7, C11, C12, C14, C18, C27, C43	0.47 µF Capacitor, 0402 Pkg.
C4, C13	22 pF Capacitor, 0402 Pkg.
C5, C33	1000 pF Capacitor, 0402 Pkg.
C8	1.5 pF Capacitor, 0402 Pkg.
C19 - C24, C28, C30 - C32, C34	0.1 µF Capacitor, 0402 Pkg.
C26	1.0 µF Capacitor, 0603 Pkg.
C35	3300 pF Capacitor, 0402 Pkg.
C36	270 pF Capacitor, 0402 Pkg.
C37, C38	68 pF Capacitor, 0402 Pkg.
C39 - C42	4.7 µF Tantalum Capacitor, 0805 Pkg
FB1 - FB2	1000 Ohm 200 mA Ferrite Chip, 0805 Pkg.
R1, R2, R5, R11, R15, R18, R19	Zero Ohm Resistor, 0402 Pkg.
R3, R4, R6, R7	1 kOhm Resistor, 0402 Pkg.
R8	22 Ohm Resistor, 0402 Pkg.
R12, R20, R23	51 Ohm Resistor, 0402 Pkg.
R22, R25	20 kOhm Resistor, 0402 Pkg.
R24	10 Ohm Resistor, 0402 Pkg.
R26 - R28	1k Ohm Resistor, 0402 Pkg.
L1	12 nH Inductor, 0402 Pkg.
TP3, TP4	Test Point PC Compact SMT
U1	HMC826LP6CE PLL with Integrated VCO
U2	Low Noise Quad Adjustable Linear Regulator
Y1	3.3V, 50 MHz VCXO Crystal Oscillator
PCB [2]	125998 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR and FR4